



HMPSA14

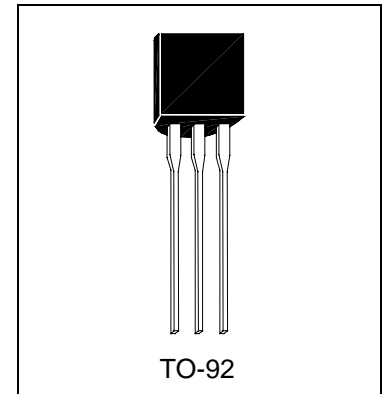
NPN SILICON TRANSISTOR

Description

The HMPSA14 is designed for applications requiring extremely high current gain collector current to 500mA.

Features

- High D.C current Gain
- HMPSA14 Complementary to HMPSA64



Absolute Maximum Ratings

- Maximum Temperatures
 Storage Temperature -55 ~ +150 °C
 Junction Temperature +150 °C Maximum
- Maximum Power Dissipation
 Total Power Dissipation (Ta=25°C) 625 mW
- Maximum Voltages and Currents (Ta=25°C)
 VCBO Collector to Base Voltage 30 V
 VCES Collector to Emitter Voltage 30 V
 VEBO Emitter to Base Voltage 10 V
 IC Collector Current 500 mA

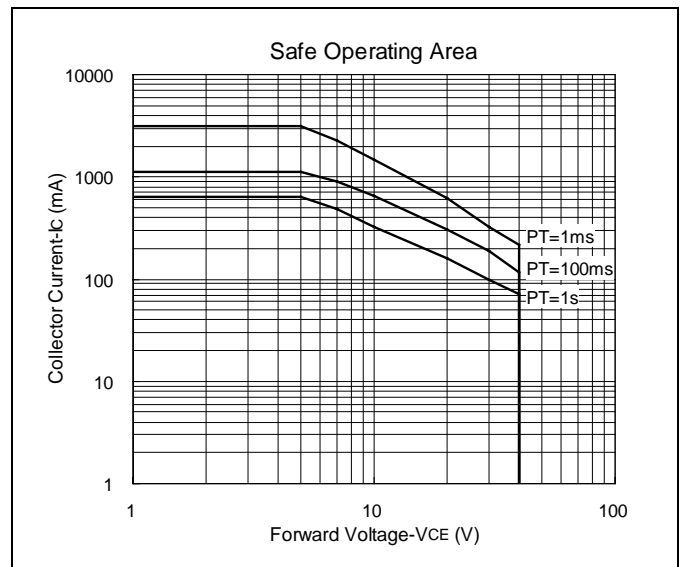
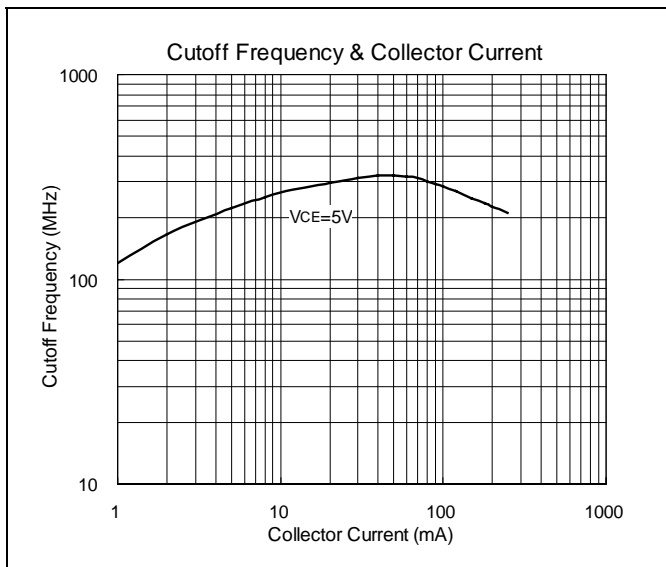
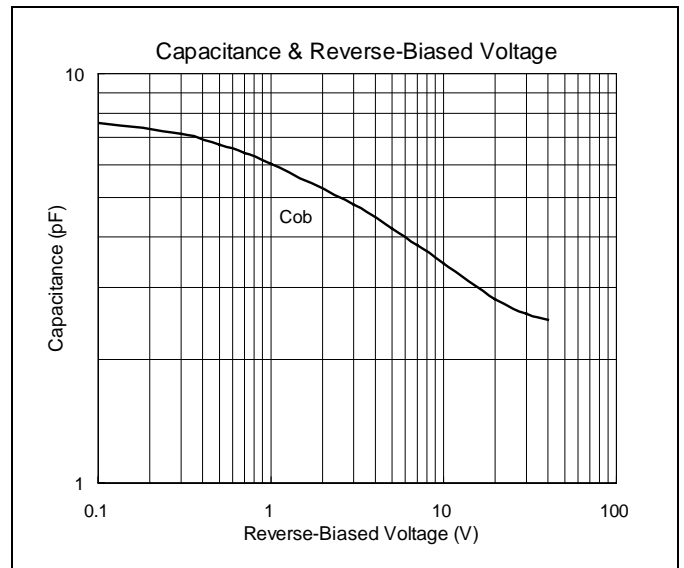
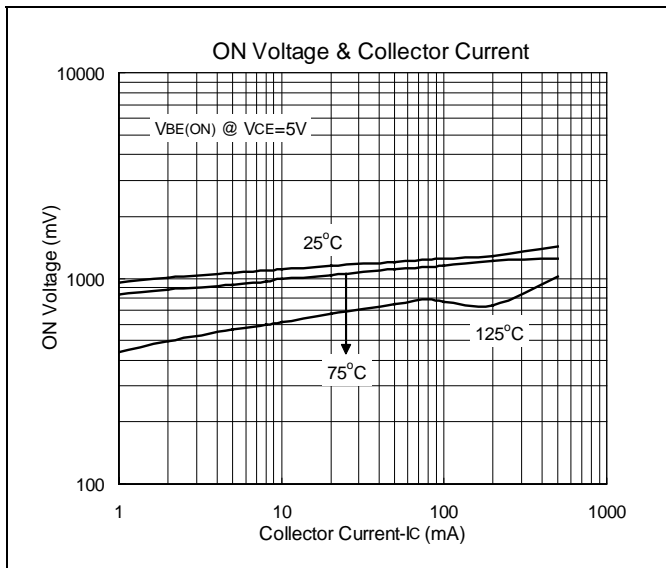
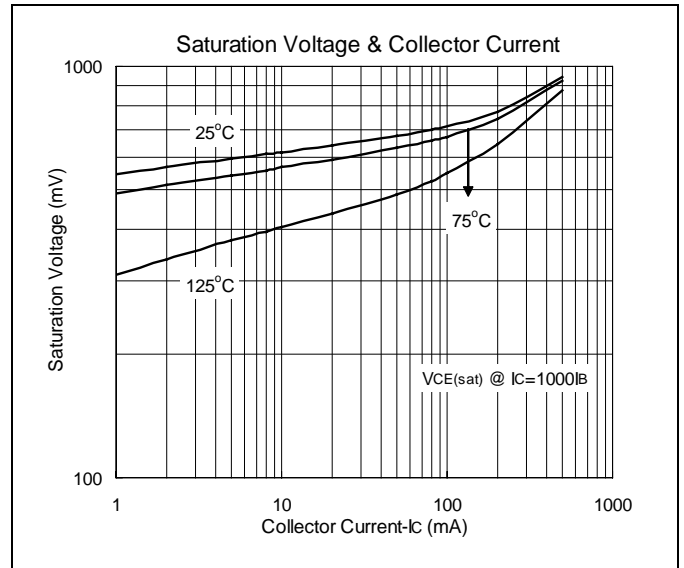
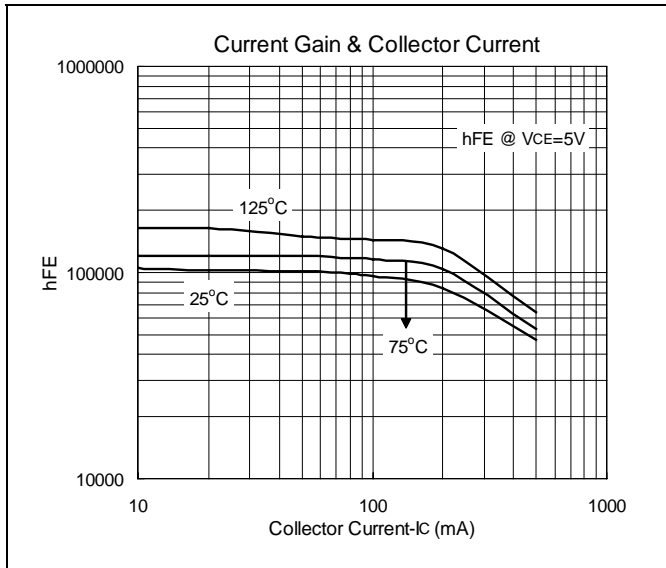
Characteristics (Ta=25°C)

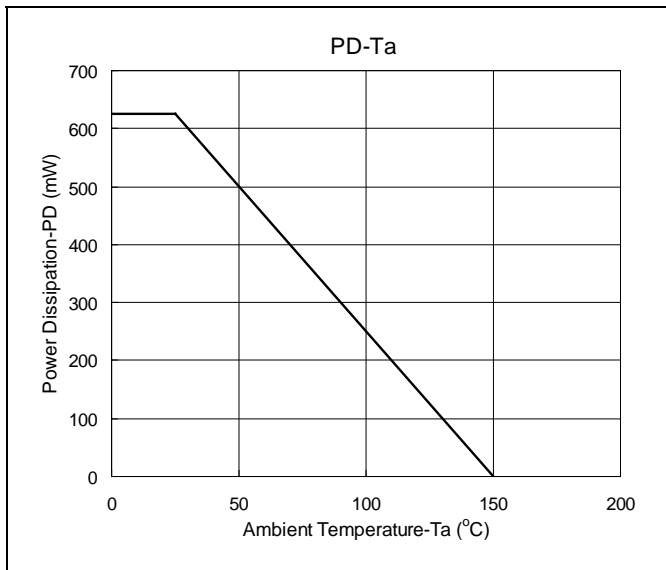
| Symbol | Min. | Typ. | Max. | Unit | Test Conditions |
|-----------|------|------|------|------|---------------------------|
| BVCBO | 30 | - | - | V | IC=100uA, IE=0 |
| BVCES | 30 | - | - | V | IC=0.1mA, VBE=0 |
| BVEBO | 10 | - | - | V | IE=10uA, IC=0 |
| ICBO | - | - | 100 | nA | VCB=30V, IE=0 |
| IEBO | - | - | 100 | nA | VEB=10V, IC=0 |
| *VCE(sat) | - | - | 1.5 | V | IC=100mA, IB=0.1mA |
| VBE(on) | - | - | 2 | V | VCE=5V, IC=100mA |
| *hFE1 | 10K | - | - | | IC=10mA, VCE=5V |
| *hFE2 | 20K | - | - | | IC=100mA, VCE=5V |
| fT | 125 | - | - | MHz | IC=10mA, VCE=5V, f=100MHz |
| Cob | - | - | 6 | pF | VCB=10V, f=1MHz |

*Pulse Test: Pulse Width ≤380us, Duty Cycle≤2%



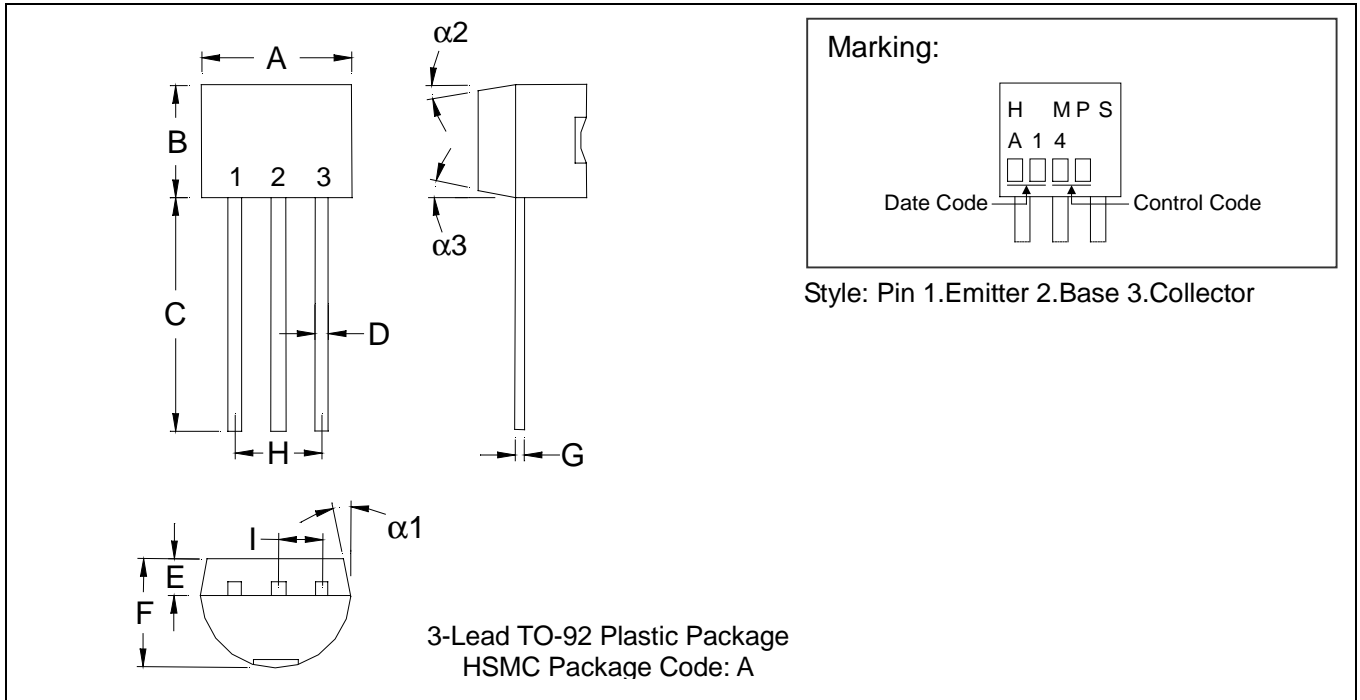
Characteristics Curve







TO-92 Dimension



*: Typical

| DIM | Inches | | Millimeters | | DIM | Inches | | Millimeters | |
|-----|--------|---------|-------------|-------|------------|--------|---------|-------------|-------|
| | Min. | Max. | Min. | Max. | | Min. | Max. | Min. | Max. |
| A | 0.1704 | 0.1902 | 4.33 | 4.83 | G | 0.0142 | 0.0220 | 0.36 | 0.56 |
| B | 0.1704 | 0.1902 | 4.33 | 4.83 | H | - | *0.1000 | - | *2.54 |
| C | 0.5000 | - | 12.70 | - | I | - | *0.0500 | - | *1.27 |
| D | 0.0142 | 0.0220 | 0.36 | 0.56 | $\alpha 1$ | - | *5° | - | *5° |
| E | - | *0.0500 | - | *1.27 | $\alpha 2$ | - | *2° | - | *2° |
| F | 0.1323 | 0.1480 | 3.36 | 3.76 | $\alpha 3$ | - | *2° | - | *2° |

Notes: 1.Dimension and tolerance based on our Spec. dated Apr. 25,1996.
 2.Controlling dimension: millimeters.
 3.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
 4.If there is any question with packing specification or packing method, please contact your local HSMC sales office.

Material:

- Lead: 42 Alloy; solder plating
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

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